

FEATURES

| Advanced trench cell design

| Low Thermal Resistance

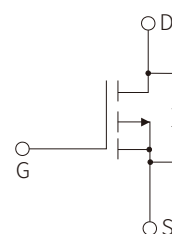
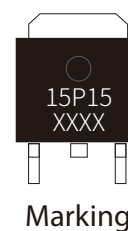
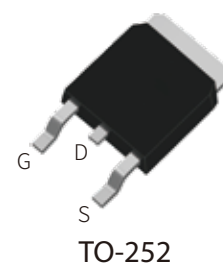
APPLICATION

| Motor drivers

| DC - DC Converter

APPROVALS

RoHS	Compliance with 2011/65/EU
HF	Compliance with IEC61249-2-21:2003



Schematic Symbol

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Drain-Source Voltage $T_c=25^\circ\text{C}$	V_{DS}	-150	V
Pulsed Source Current $T_c=25^\circ\text{C}, V_{GS}=-10\text{V}$	I_{DM}^{***}	-60	A
Drain Current $T_c=25^\circ\text{C}, V_{GS}=-10\text{V}$	I_D^{***}	-15	A
Gate-Source Voltage $T_c=25^\circ\text{C}$	V_{GS}	± 20	V
Total Power Dissipation $T_c=25^\circ\text{C}$	P_{tot}^*	89	W
Diode Forward Current $T_c=25^\circ\text{C}$	I_S	-15	A
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^\circ\text{C}$
Thermal Resistance- Junction to Ambient	$R_{\theta JC}^*$	62.5	$^\circ\text{C/W}$

Notes:

* Surface Mounted on 1 in² pad area, $t \leq 10$ sec

** Pulse width $\leq 10\mu\text{s}$, duty cycle $\leq 1\%$

*** Limited by bonding wire

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-150			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_{DS}=-250\mu A$	-1		-3	V
Zero Gate Voltage Source Current	I_{DSS}	$V_{DS}=-120V, V_{GS}=0V$			-25	μA
		$V_{DS}=-120V, V_{GS}=0V, T_J=85^{\circ}C$			-30	μA
Gate Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			± 100	nA
Drain-Source On-State Resistance	$R_{DS(on)}^a$	$V_{GS}=-10V, I_D=-12A$		140	160	m Ω
Diode Characteristics						
Diode Forward Voltage	V_{SD}^a	$I_{SD}=-12A, V_{GS}=0V$			-1.3	V
Reverse Recovery Time	t_{rr}	$I_{SD}=-12A,$ $dI_{SD}/dt=100A/\mu s$		75		nS
Reverse Recovery Charge	Q_{rr}			250		nC
Dynamic Characteristics ^b						
Input capacitance	C_{iss}	$V_{GS}=0V, V_{DS}=-25V,$ Frequency = 1 MHz		2850	4560	pF
Output capacitance	C_{oss}			150		pF
Reverse transfer capacitance	C_{rss}			100		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DS}=-50V, V_{GEN}=-10V$ $R_G=3.3\Omega, I_D=-10A$		11		nS
Turn-on Rise Time	t_r			26		nS
Turn-Off Delay Time	$t_{d(off)}$			67		nS
Turn-Off Fall Time	t_f			60		nS
Gate Charge Characteristics ^b						
Total Gate Charge	Q_g	$V_{DS}=-80V, V_{GS}=-10V, I_{DS}=-12A$		55	90	nC
Gate-Source Charge	Q_{gs}			8.2		nC
Gate-Drain Charge	Q_{gd}			16.6		nC

Notes:

a : Pulse test ; pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

PARAMETER CHARACTERISTIC CURVE

Figure1: Power Capability

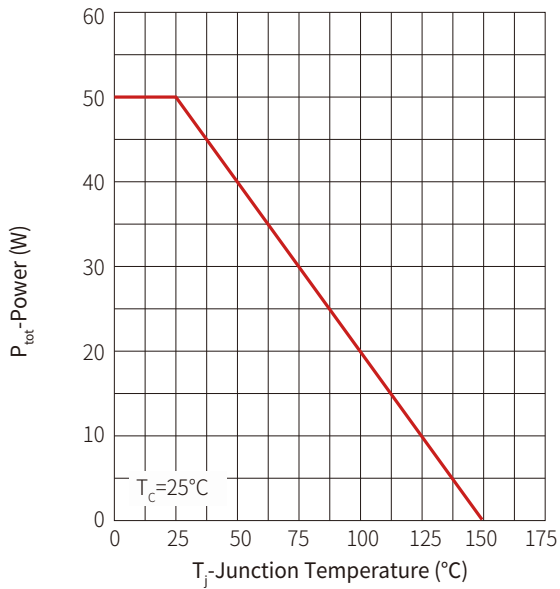


Figure2: Current Capability

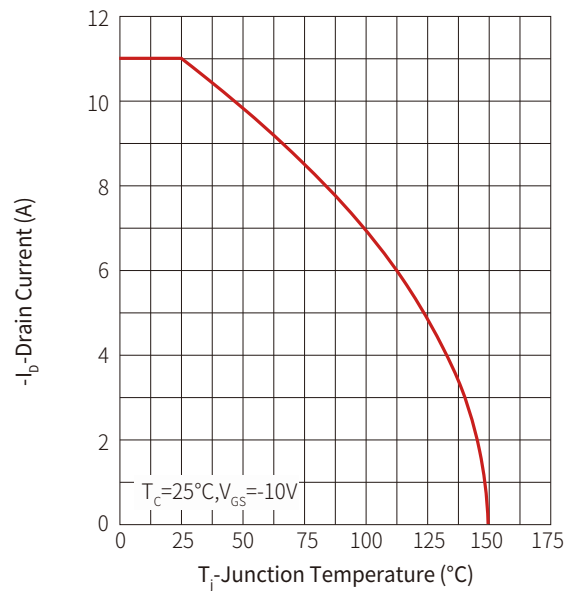


Figure3: Safe operating Area

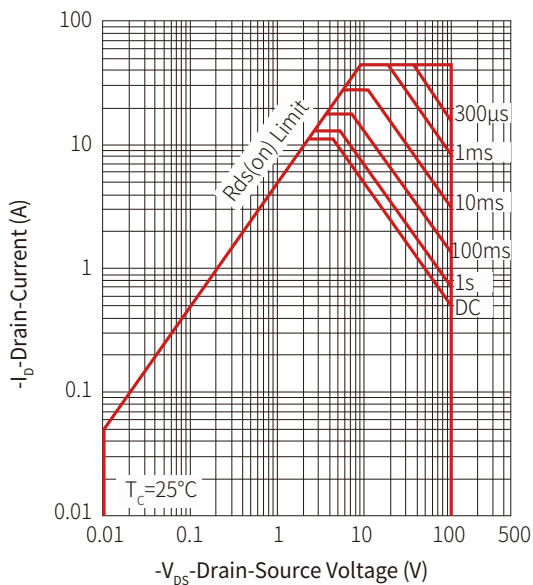


Figure 4: Transient Thermal Impedance

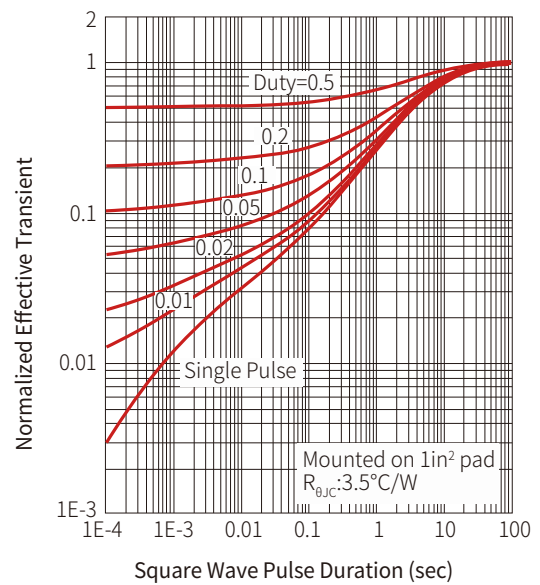


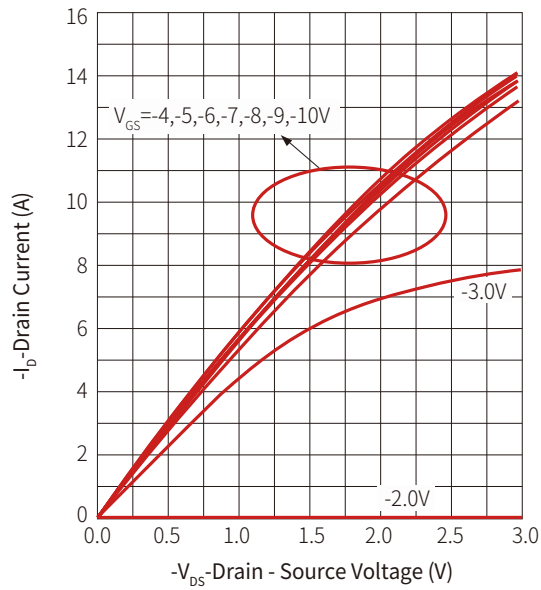
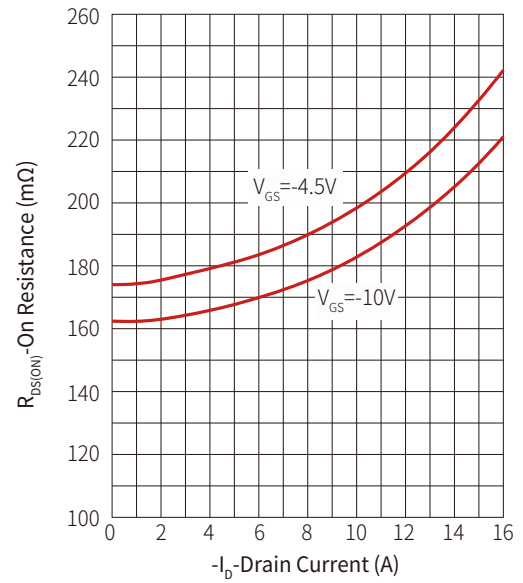
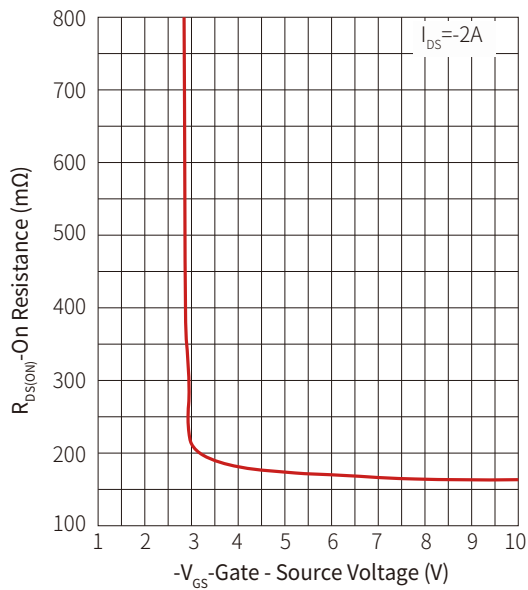
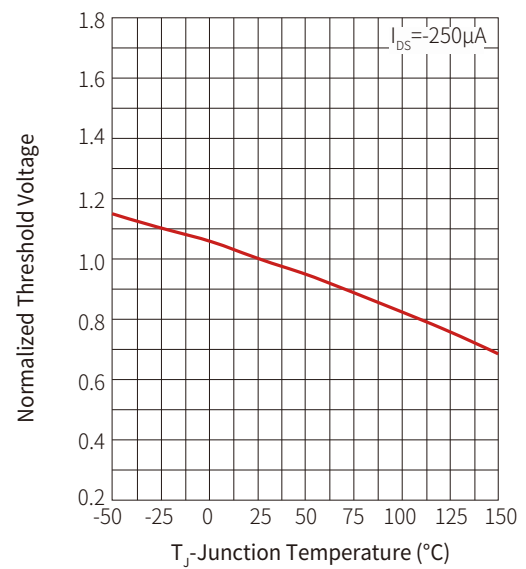
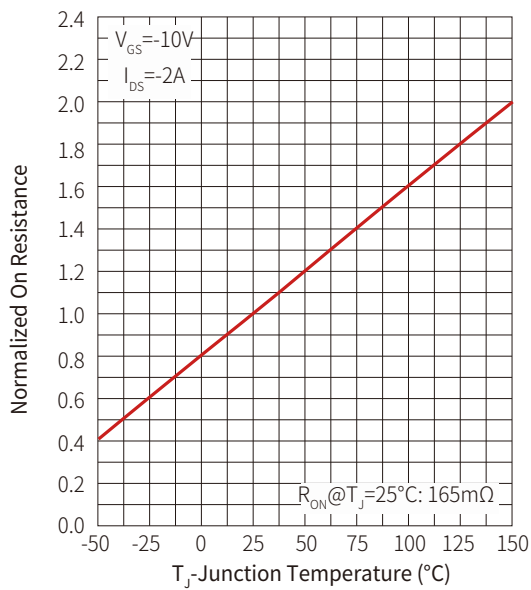
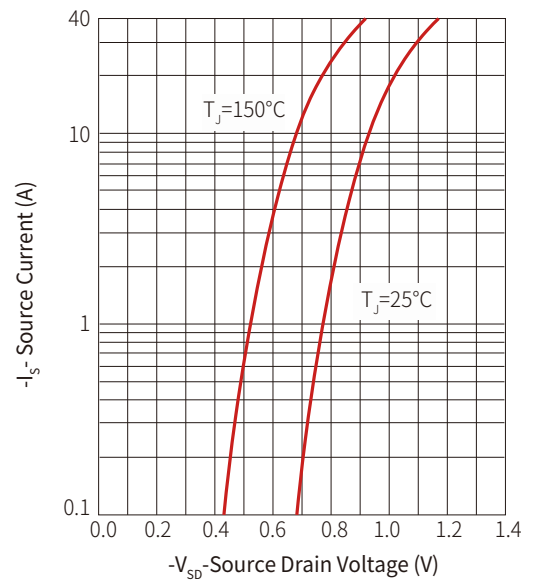
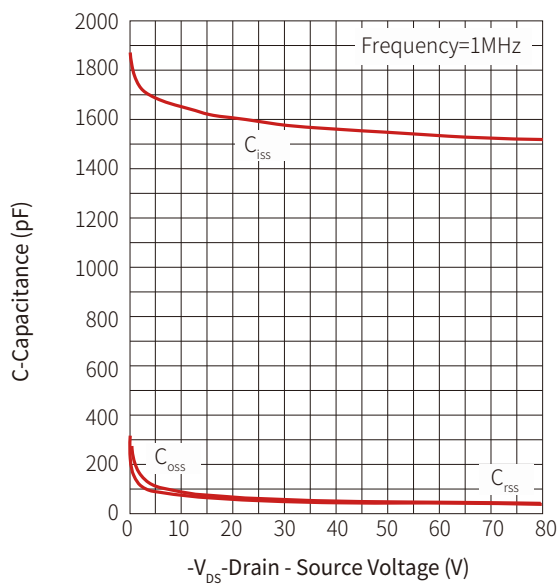
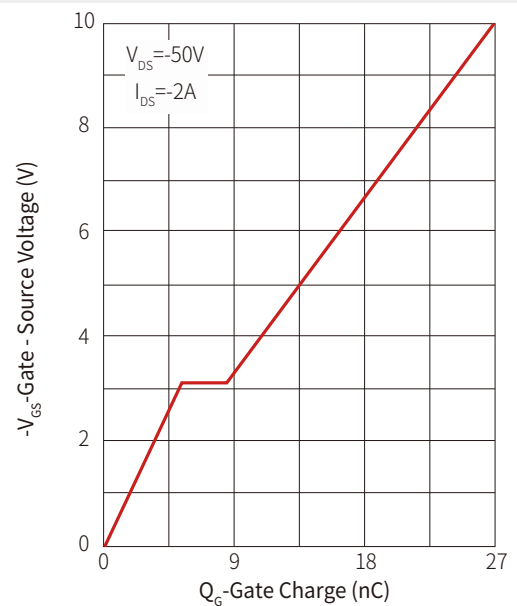
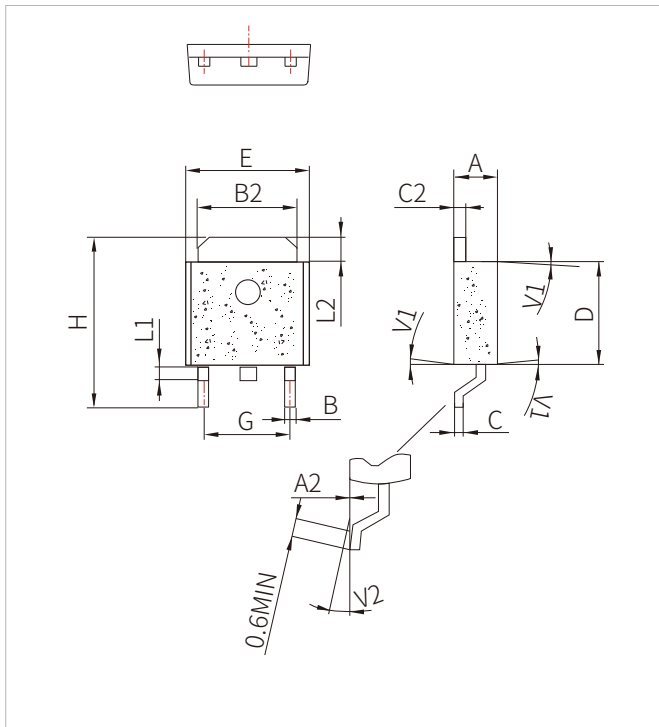
Figure 5: Output Characteristics

Figure 6: Drain-Source On Resistance

Figure 7: Transfer Characteristics

Figure 8: Normalized Threshold Voltage


Figure 9: Normalized On Resistance

Figure 10: Diode Forward Current

Figure 11: Capacitance

Figure 12: Gate Charge


TO-252 PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0.03		0.23	0.001		0.009
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.80	0.252		0.268
G	4.40		4.70	0.173	0.1	0.185
H	9.35		10.7	0.368		0.421
L1	1.30		1.70	0.051	0.143	0.067
L2	1.37		1.50	0.054		0.059
V1		4°			0.130	
V2	0°		8°	0°		8°

ORDERING INFORMATION

Part Number	Component Package	QTY/Reel	Reel Size
SPM15P15K	TO-252	2500PCS	13"

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